# NSN 5961-01-248-6925

Transistor - Page 1 of 1



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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.803 inches

## **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

**Overall Width Across Flats:** 

0.875 inches

Thread Size:

# 0.312 inches

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

150.0 breakdown voltage, collector-to-base, emitter open and 150.0 breakdown voltage, collector-to-emitter, with specified circuit between base and emitter and 15.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 10.00 amperes source cutoff current and 10.00 amperes source cutoff current blank

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### Test Data Document:

10001-3151216 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

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